

MOSFETs Silicon N-Channel MOS

SSM3K318R

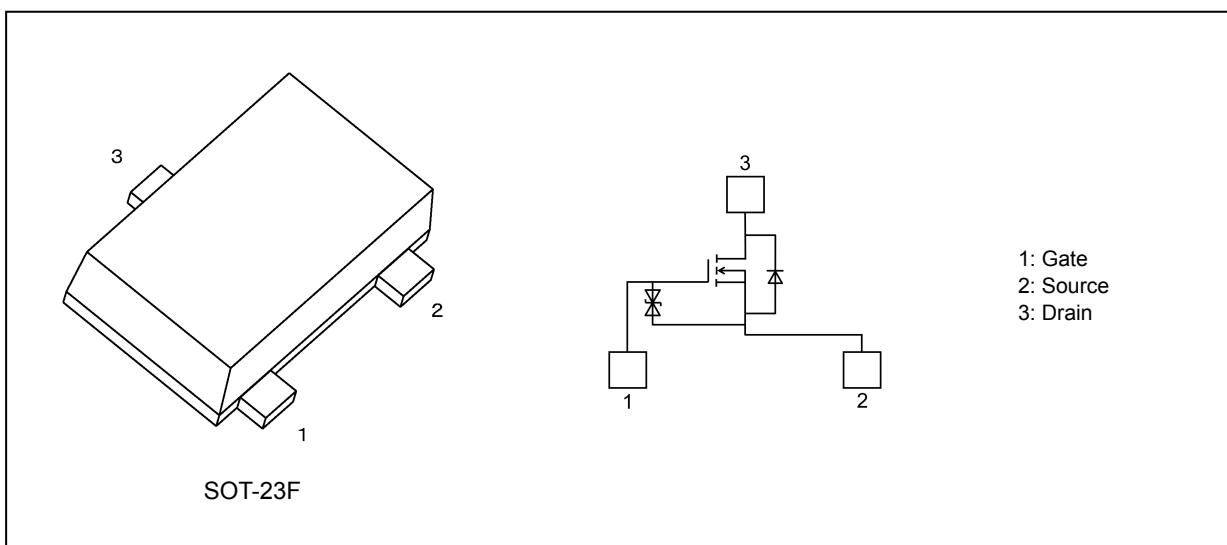
1. Applications

- Load Switches
- Ultra-High-Speed Switching

2. Features

- (1) 4.5-V gate drive voltage.
- (2) Low drain-source on-resistance
 $R_{DS(ON)} = 145 \text{ m}\Omega$ (max) (@ $V_{GS} = 4.5 \text{ V}$)
 $R_{DS(ON)} = 107 \text{ m}\Omega$ (max) (@ $V_{GS} = 10 \text{ V}$)

3. Packaging and Pin Assignment



Start of commercial production
2015-02

4. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	60	V
Gate-source voltage	V_{GSS}	± 20	
Drain current (Note 1)	I_D	2.5	A
Drain current (pulsed) (Note 1)	I_{DP}	5	
Power dissipation (Note 2)	P_D	1	W
Power dissipation ($t = 10\text{ s}$) (Note 2)	P_D	2	
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: Ensure that the channel temperature does not exceed 150°C .

Note 2: Device mounted on an FR4 board. ($25.4\text{ mm} \times 25.4\text{ mm} \times 1.6\text{ mm}$, Cu pad: 645 mm^2)

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance, $R_{th(ch-a)}$, and the drain power dissipation, P_D , vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-ambient thermal resistance (Note 1)	$R_{th(ch-a)}$	125	$^\circ\text{C/W}$

Note 1: Device mounted on an $25.4\text{ mm} \times 25.4\text{ mm} \times 1.6\text{ mm}$ FR4 glass epoxy board (Cu pad: 645 mm^2)

6. Electrical Characteristics

6.1. Static Characteristics (Unless otherwise specified, $T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 1	μA
Drain cut-off current	I_{DSS}	$V_{DS} = 60\text{ V}, V_{GS} = 0\text{ V}$	—	—	1	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	60	—	—	V
Drain-source breakdown voltage (Note 1)	$V_{(BR)DSX}$	$I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$	35	—	—	
Gate threshold voltage (Note 2)	V_{th}	$V_{DS} = 5\text{ V}, I_D = 1\text{ mA}$	1.8	—	2.8	
Drain-source on-resistance (Note 3)	$R_{DS(\text{ON})}$	$I_D = 2.0\text{ A}, V_{GS} = 10\text{ V}$	—	83.5	107	$\text{m}\Omega$
		$I_D = 1.0\text{ A}, V_{GS} = 4.5\text{ V}$	—	101	145	
Forward transfer admittance (Note 3)	$ Y_{fs} $	$V_{DS} = 5\text{ V}, I_D = 2\text{ A}$	3.7	7.4	—	S

Note 1: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

Note 2: Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (1 mA for this device). Then, for normal switching operation, $V_{GS(\text{ON})}$ must be higher than V_{th} , and $V_{GS(\text{OFF})}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(\text{OFF})} < V_{th} < V_{GS(\text{ON})}$.

Take this into consideration when using the device.

Note 3: Pulse measurement.

6.2. Dynamic Characteristics (Unless otherwise specified, $T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	$V_{DS} = 30\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	235	—	pF
Reverse transfer capacitance	C_{rss}		—	23	—	
Output capacitance	C_{oss}		—	31	—	
Switching time (turn-on time)	t_{on}	$V_{DD} = 30\text{ V}, I_D = 1\text{ A}, V_{GS} = 0\text{ to }4.5\text{ V}, R_{GS} = 10\Omega$	—	14	—	ns
Switching time (turn-off time)	t_{off}		—	9.5	—	

6.3. Switching Time Test Circuit

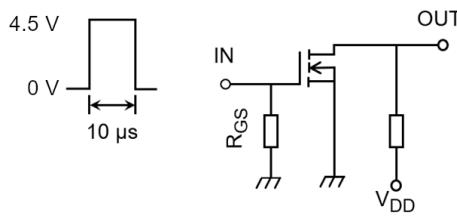


Fig. 6.3.1 Switching Time Test Circuit

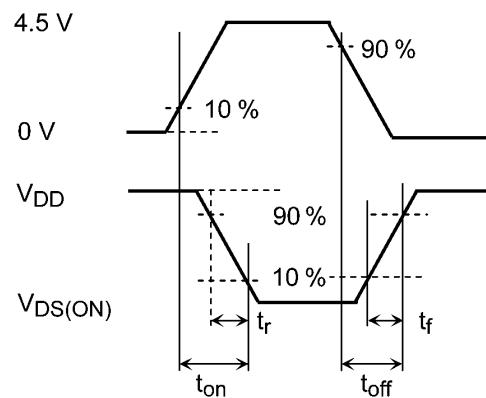


Fig. 6.3.2 Input Waveform/Output Waveform

6.4. Gate Charge Characteristics (Unless otherwise specified, $T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} = 30\text{ V}, I_D = 2.5\text{ A}, V_{GS} = 10\text{ V}$	—	7	—	nC
Gate-source charge	Q_{gs}		—	4.8	—	
Gate-drain charge	Q_{gd}		—	2.2	—	

6.5. Source-Drain Characteristics (Unless otherwise specified, $T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Diode forward voltage (Note 1)	V_{DSF}	$I_{DR} = 2.5\text{ A}, V_{GS} = 0\text{ V}$	—	0.83	1.2	V

Note 1: Pulse measurement.

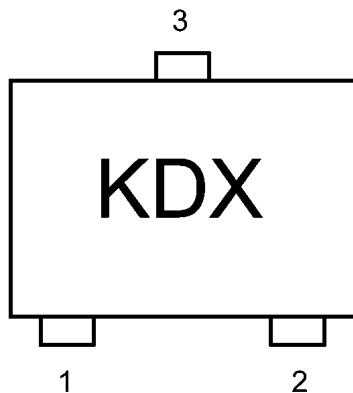
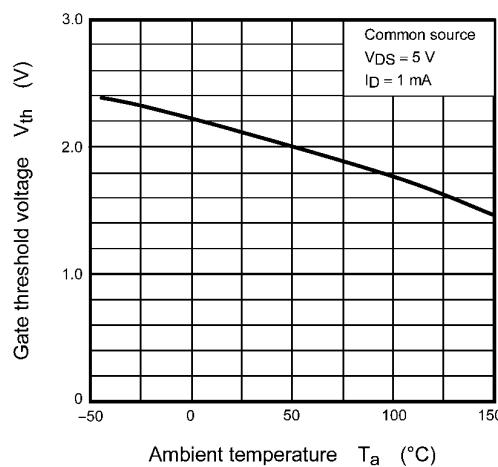
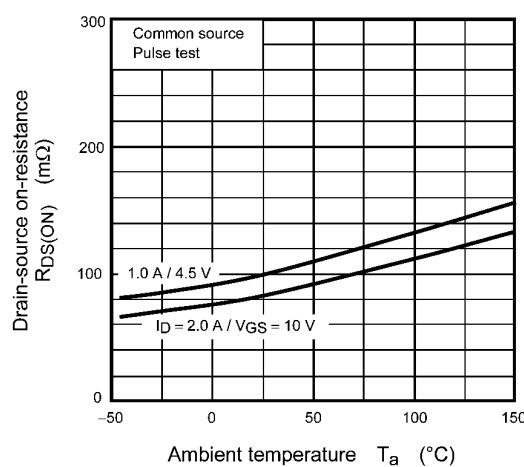
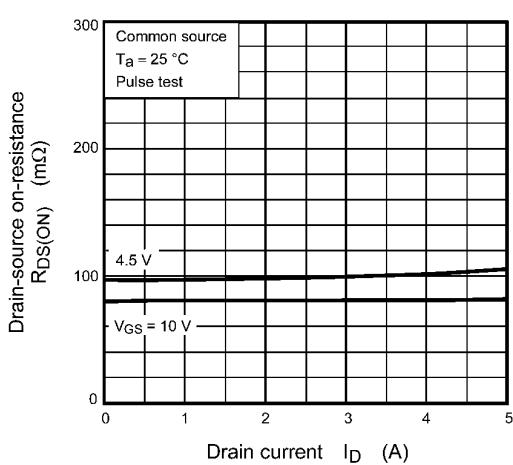
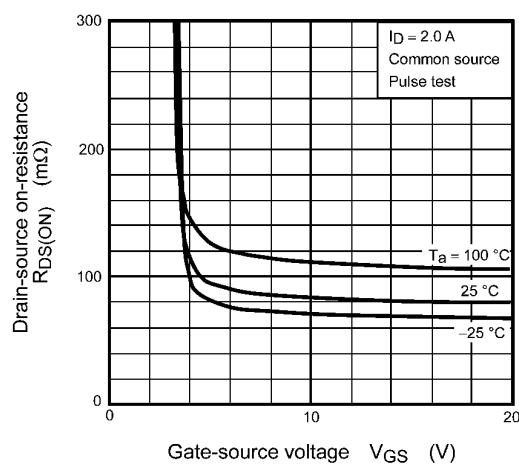
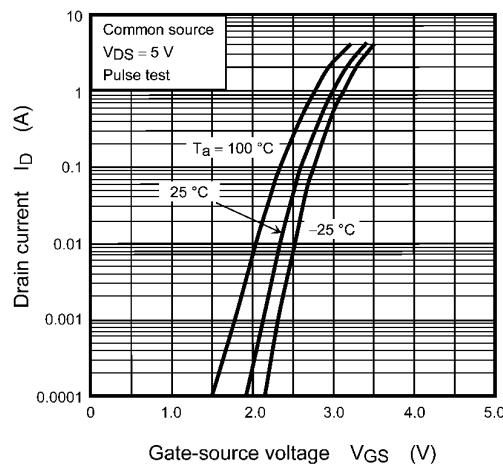
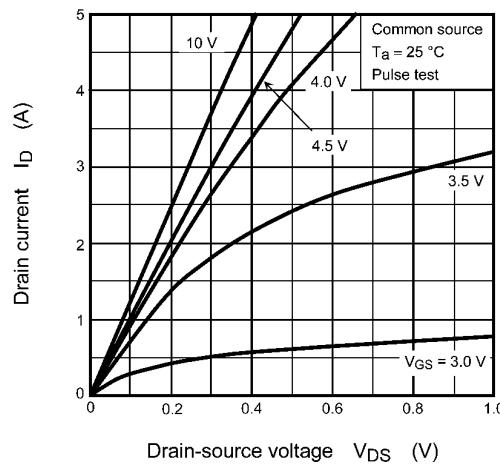
7. Marking

Fig. 7.1 Marking

8. Characteristics Curves (Note)



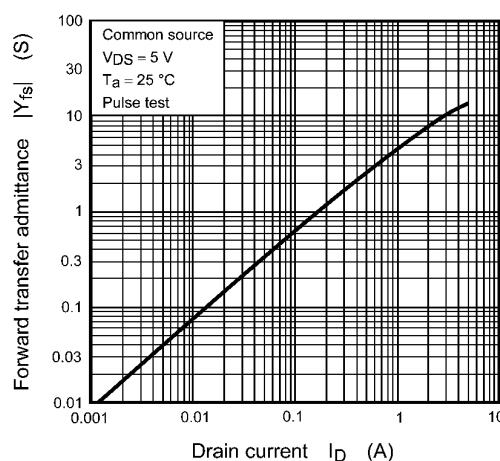


Fig. 8.7 |Y_{fs}| - I_D

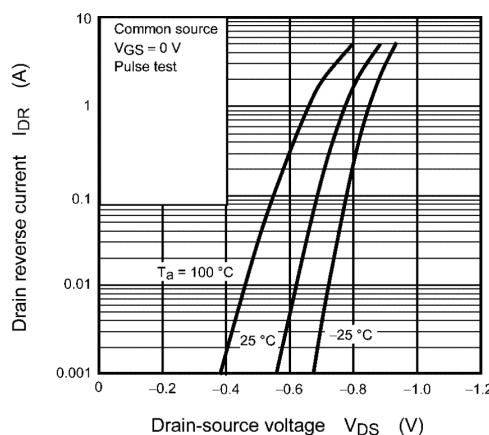


Fig. 8.8 I_{DR} - V_{DS}

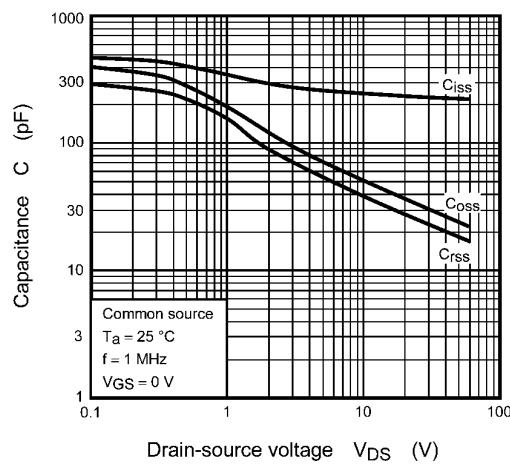


Fig. 8.9 C - V_{DS}

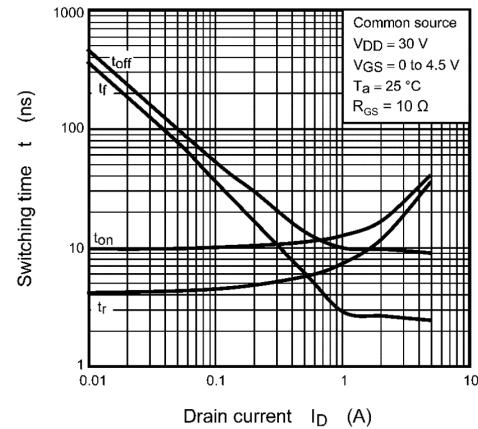


Fig. 8.10 t - I_D

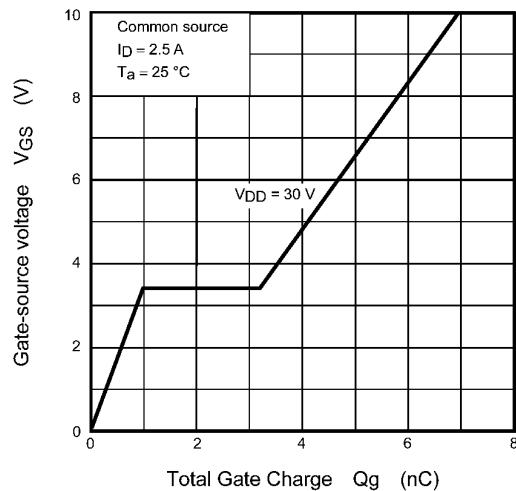


Fig. 8.11 Dynamic Input Characteristics

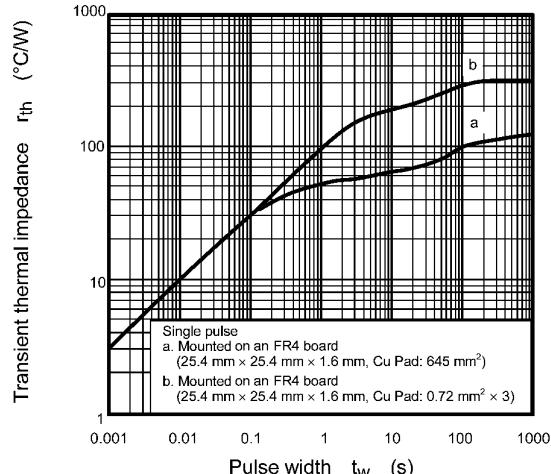


Fig. 8.12 r_{th} - t_w

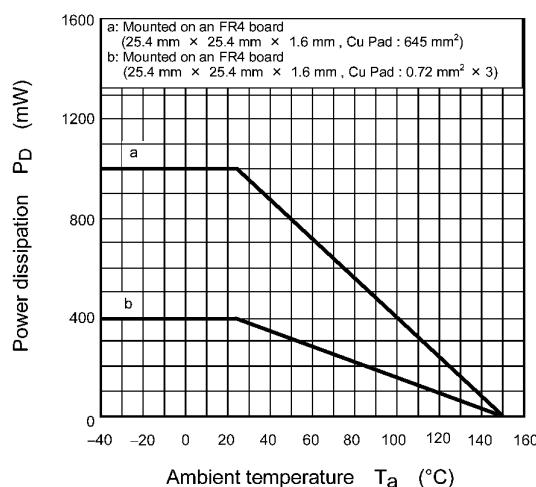
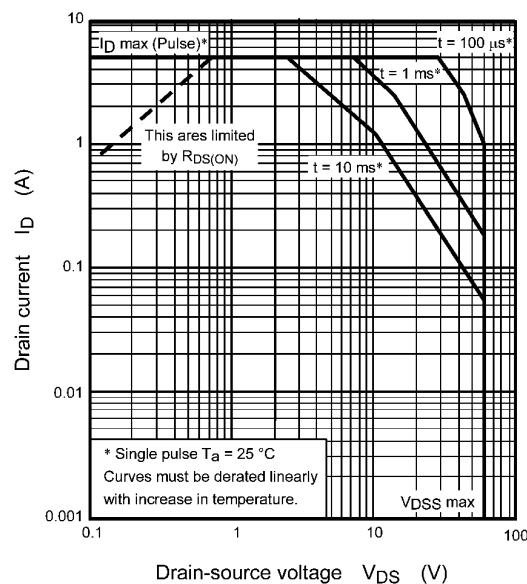
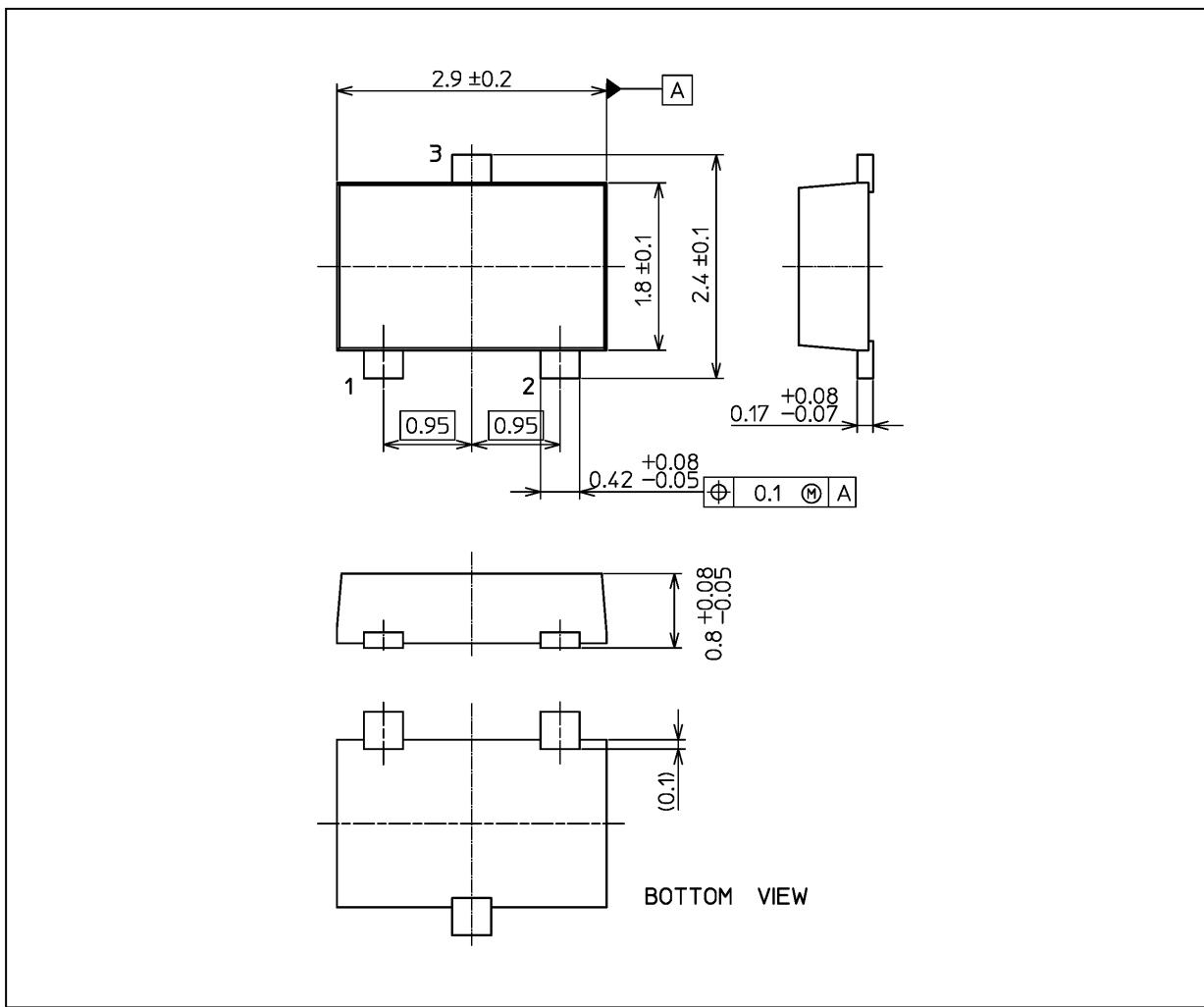
Fig. 8.13 P_D - T_a 

Fig. 8.14 Safe Operating Area

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.011 g (typ.)

Package Name(s)
Nickname: SOT-23F

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